

P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I _D (A)	Q _g (Typ.)			
- 60	0.050 at V _{GS} = - 10 V	- 12 ^d	20 nC			
- 60	0.060 at V _{GS} =-4.5 V	- 9 ^d	20110			

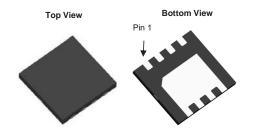
DFN 3x3 EP

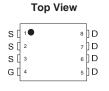
FEATURES

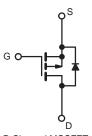
- DT-Trench Power MOSFET
- Low On-Resistance for Low Voltage Drop
- 100 % R_g and UIS Tested

APPLICATIONS

- Battery, Load and Adaptor Switches
 - Notebook Computers
 - Notebook Battery Packs







P-Channel MOSFET

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	V
Gate-Source Voltage		V _{GS}	± 20	v
	T _C = 25 °C		- 12 ^d	
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 70 °C		_ 9	
Continuous Diam Curient (1) = 130 °C)	T _A = 25 °C	- I _D	-4.1 ^{a, b}	
	T _A = 70 °C		- 2.5 ^{a, b}	Α
Pulsed Drain Current (t = 100 µs)	I _{DM}	- 48	A	
Continuous Source Drain Diede Current	T _C = 25 °C	I-	- 12 ^d	
Continuous Source-Drain Diode Current	T _A = 25 °C	- I _S	- 1.1 ^{a, b}	
Avalanche Current	1 0411	I _{AS}	- 18	
Single-Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	15	mJ
	T _C = 25 °C		42	
Manianus Davies Dissination	T _C = 70 °C		13	14/
Maximum Power Dissipation	T _A = 25 °C	P _D	3.2 ^{a, b}	W
	T _A = 70 °C	1	2.1 ^{a, b}	
Operating Junction and Storage Temperature Rang	T _J , T _{stq}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{a, c}	t ≤ 10 s	R _{thJA}	21	30	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	2.1	2.7	C/VV	

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. t = 10 s.
- c. Maximum under steady state conditions is 70 °C/W.
- d. Package limited.
- e. The DFN3X3 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
					l	
V _{DS}	$V_{GS} = 0, I_D = -250 \mu A$	- 60			V	
$\Delta V_{DS}/T_{J}$	J 050 A		- 20		mV/°C	
$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		3.6			
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 1		- 3	V	
I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
I _{DSS}	V _{DS} = - 48 V, V _{GS} = 0 V			- 1	uA	
	V _{DS} = - 48 V, V _{GS} = 0 V, T _J = 55 °C			- 5		
I _{D(on)}		- 48			Α	
R _{DS(on)}	V _{GS} = - 10 V, I _D = - 5 A	_	0.050	0.056	+	
	V _{GS} = - 4.5 V, I _D = - 5 A				Ω	
9 _{fs}	V _{DS} = - 10 V, I _D = - 5 A		20		S	
		l .				
C _{iss}			1750		pF	
	V _{DS} = - 48 V, V _{GS} = 0 V, f = 1 MHz					
Qg	V _{DS} = -48 V, V _{GS} = -10 V, I _D = -5 A				+	
Q _{gs}	V _{DS} = - 48 V, V _{GS} = - 4.5 V, I _D = - 5 A		8.6		- nC	
Q _{gd}			28.8			
R _g	f = 1 MHz		1.3		Ω	
t _{d(on)}			12			
t _r	$V_{DS} = -48 \text{ V}, R_{L} = 3.5 \Omega$		10			
t _{d(off)}	$I_D \cong -5 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		29			
t _f			7			
t _{d(on)}			29		ns	
t _r	$V_{DD} = -48 \text{ V}, R_{L} = 3.5 \Omega$		30		- - -	
t _{d(off)}	$I_{D} \cong -5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_{g} = 1 \Omega$		22			
t _f	1		17			
ics	1					
I _S	T _C = 25 °C			- 12	A	
I _{SM}				- 48		
V_{SD}	I _S = -3 A, V _{GS} = 0		- 0.7	- 1	V	
t _{rr}			21		ns	
Q _{rr}	In = - 5 A. dl/dt = 100 A/us, Tu = 25 °C		50		nC	
t _a			9	1	ns	
	ΔV _{DS} /T _J ΔV _{GS(th)} /T _J V _{GS(th)} /T _J V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)} gfs C _{iss} C _{oss} C _{rss} Q _g Q _{gd} R _g t _{d(on)} t _r t _{d(off)} t _f t _{d(off)} t _f tics I _S	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

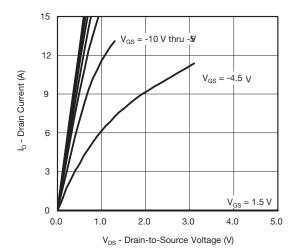
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

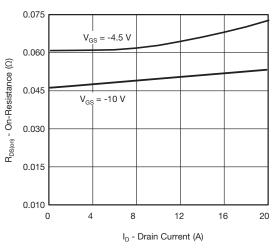
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

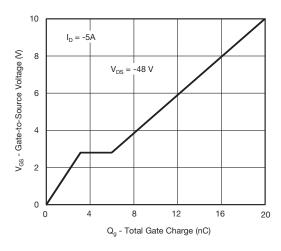




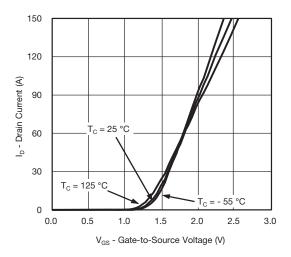
Output Characteristics



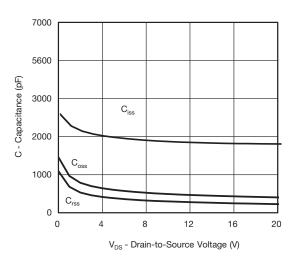
On-Resistance vs. Drain Current



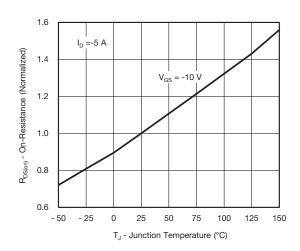
Gate Charge



Transfer Characteristics

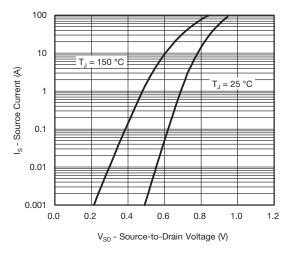


Capacitance

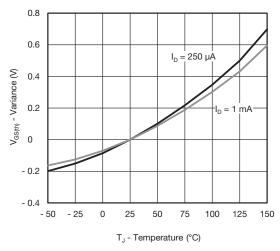


On-Resistance vs. Junction Temperature

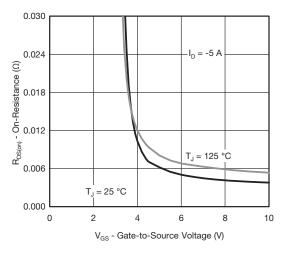




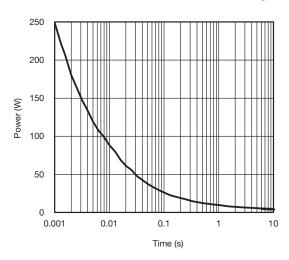
Source-Drain Diode Forward Voltage



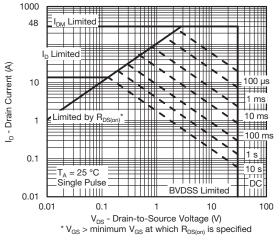
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

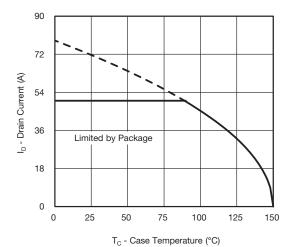


Single Pulse Power, Junction-to-Ambient

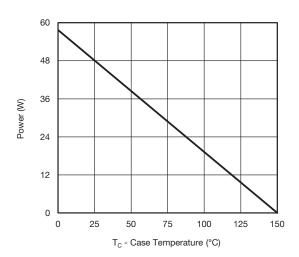


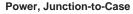
Safe Operating Area

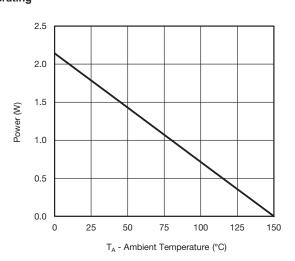




Current Derating*



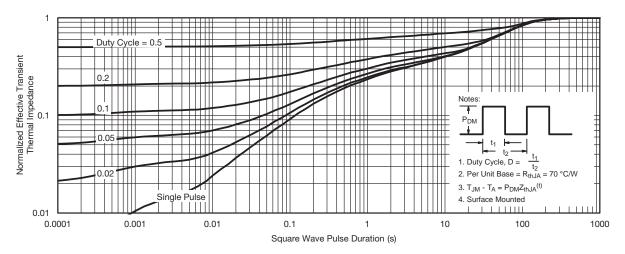




Power Derating, Junction-to-Ambient

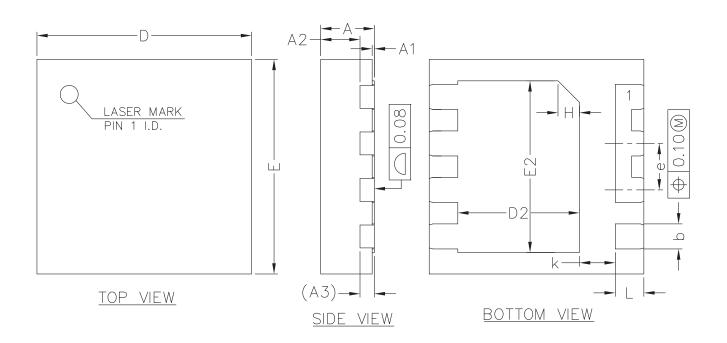
^{*} The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient







COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
Α	0.70	0.75	0.80	
A1	0.00	0.02	0.05	
A2	0.50	0.55	0.60	
А3	0.20REF			
Ь	0.30	0.35	0.40	
D	2.90	3.00	3.10	
Е	2.90	3.00	3.10	
D2	1.60	1.70	1.80	
E2	2.30	2.40	2.50	
е	0.55	0.65	0.75	
K	0.40	0.50	0.60	
L	0.35	0.40	0.45	



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